

SLLS829C - APRIL 2007 - REVISED MARCH 2011

RS-232 TRANSCEIVER WITH SPLIT SUPPLY PIN FOR LOGIC SIDE

Check for Samples: TRS3386E

FEATURES

- V_L Pin for Compatibility With Mixed-Voltage Systems Down to 2.5 V on Logic Side
- Enhanced ESD Protection on RIN Inputs and DOUT Outputs
 - ±15-kV Human-Body Model
 - ±15-kV IEC 61000-4-2, Air-Gap Discharge
 - ±8-kV IEC 61000-4-2, Contact Discharge
- Low 300-µA Supply Current
- Specified 250-kbps Data Rate
- 1-µA Low-Power Shutdown
- Meets EIA/TIA-232 Specifications Down to 3 V
- Designed to be Interchangeable With Industry Standard '3386 Devices

APPLICATIONS

- Hand-Held Equipment
- PDAs
- Cell Phones
- Battery-Powered Equipment
- Data Cables

	PW	OR DW PACKA TOP VIEW	GE
V+2 19 V _{CC} C1-3 18 GND C2+4 17 DOUT1 C2-5 16 DOUT2 V-6 15 DOUT3 DIN17 14 RIN1 DIN28 13 RIN2 DIN39 12 V _L ROUT210 11 ROUT1	C1-3 C2+4 C2-5 V-6 DIN17 DIN28 DIN39	•	18 GND 17 DOUT1 16 DOUT2 15 DOUT3 14 RIN1 13 RIN2 12 V _L

DESCRIPTION/ORDERING INFORMATION

The TRS3386E is a three-driver and two-receiver RS-232 interface device, with split supply pins for mixed-signal operations. All RS-232 inputs and outputs are protected to ± 15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ± 8 kV using the IEC 61000-4-2 Contact Discharge method, and ± 15 kV using the Human-Body Model.

The charge pump requires only four small 0.1-µF capacitors for operation from a 3.3-V supply. The TRS3386E is capable of running at data rates up to 250 kbps, while maintaining RS-232-compliant output levels.

The TRS3386E has a unique V_L pin that allows operation in mixed-logic voltage systems. Both driver in (DIN) and receiver out (ROUT) logic levels are pin programmable through the V_L pin. The TRS3386E is available in a space-saving thin shrink small-outline package (TSSOP).

T _A	PACKAGE ⁽¹⁾ (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	TSSOP – PW	TRS3386ECPWR	RV86EC
0 0 10 70 0	SOIC – DW	TRS3386ECDWR	TRS3386EC
40°C to 95°C	TSSOP – PW	TRS3386EIPWR	RV86EI
–40°C to 85°C	SOIC – DW	TRS3386EIDWR	TRS3386EI

ORDERING INFORMATION

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

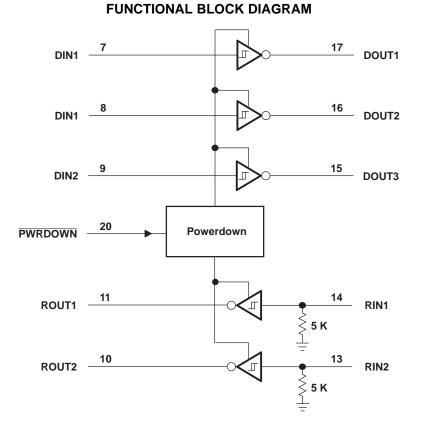


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Table 1. TRUTH TABLE (SHUTDOWN FUNCTION)						
PWRDWN DRIVER OUTPUTS		RECEIVER OUTPUTS	CHARGE PUMP			
L	High-Z	High-Z	Inactive			
Н	Active	Active	Active			

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INSTRUMENTS

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TERMINAL FUNCTIONS

TERMINAL		DESCRIPTION				
NAME	NO.	DESCRIPTION				
C1+	1	Positive terminal of the voltage-doubler charge-pump capacitor				
V+	2	5.5-V supply generated by the charge pump				
C1–	3	Negative terminal of the voltage-doubler charge-pump capacitor				
C2+	4	Positive terminal of the inverting charge-pump capacitor				
C2–	5	Negative terminal of the inverting charge-pump capacitor				
V–	6	-5.5-V supply generated by the charge pump				
DIN1 DIN2 DIN3	7 8 9	Driver inputs				
ROUT2 ROUT1	10 11	Receiver outputs. Swing between 0 and V_L .				
VL	12	Logic-level supply. All CMOS inputs and outputs are referenced to this supply.				
RIN2 RIN1	13 14	RS-232 receiver inputs				
DOUT3 DOUT2 DOUT1	15 16 17	RS-232 driver outputs				
GND	18	Ground				
V _{CC}	19	3-V to 5.5-V supply voltage				
PWRDWN	20	Powerdown input L = Powerdown H = Normal operation				

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	V _{CC} to GND		-0.3	6	V
	V _L to GND		-0.3	V _{CC} + 0.3	V
	V+ to GND		-0.3	7	V
	V- to GND			-7	V
	V+ + V- ⁽²⁾			13	V
		DIN, PWRDWN to GND	-0.3	6	v
VI	Input voltage	RIN to GND		±25	V
V		DOUT to GND		±13.2	v
Vo	Output voltage	ROUT	-0.3	V _L + 0.3	v
	Short-circuit duration DOUT to GND			Continuous	
	Continuous power dissipation	T _A = 70°C, 20-pin TSSOP (derate 7 mW/°C above 70°C)		559	mW
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C
	Lead temperature (soldering, 10 s)			300	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(2) V+ and V- can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V.

Recommended Operating Conditions

				MIN	MAX	UNIT
V _{CC}	Supply voltage			3	5.5	V
VL	Supply voltage			2.25	V_{CC}	V
	Input logic threshold low	DIN, PWRDWN	$V_L = 3 V \text{ or } 5.5 V$		0.8	V
		DIN, PWRDWN	$V_L = 2.3 V$		0.6	v
			$V_L = 5.5 V$	2.4		
Input logic threshold high	DIN, PWRDWN	$V_L = 3 V$	2.0		V	
			$V_L = 2.7 V$	1.4		
		TRS3386ECPWR	0	70	°C	
	Operating temperature		TRS3386EIPWR	-40	85	U
	Receiver input voltage			-25	25	V

Electrical Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 \text{ V}$ to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V ± 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V ± 10%) (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT		
DC Characteristics (V_{CC} = 3.3 V or 5 V, T_A = 25°C)							
Powerdown supply current	PWRDWN = GND, All inputs at V _{CC} or GND		1	10	μA		
Supply current	$\overline{PWRDWN} = V_{CC}$, No load		0.3	1	mA		

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	Human-Body Model	±15	
RIN, DOUT	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

RECEIVER SECTION

Electrical Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 V$ to 5.5 V, C1–C4 = 0.1 μ F (tested at 3.3 V ± 10%), C1 = 0.047 μ F, C2–C4 = 0.33 μ F (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER	TEST C	CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
I _{off}	Output leakage current	ROUT, receivers disab	led		±0.05	±10	μA
V _{OL}	Output voltage low	I _{OUT} = 1.6 mA				0.4	V
V _{OH}	Output voltage high	$I_{OUT} = -1 \text{ mA}$		$V_{L} - 0.6$	$V_L - 0.1$		V
V	Input throopold low	T 25°C	$V_L = 5 V$	0.8	1.2		V
V _{IT–}	Input threshold low	$T_A = 25^{\circ}C$	$V_{L} = 3.3 V$	0.6	1.5		v
V	Innut throok old bigh	T 25°C	$V_L = 5 V$		1.8	2.4	V
V _{IT+}	Input threshold high	$T_A = 25^{\circ}C$	$V_{L} = 3.3 V$		1.5	2.4	v
V _{hys}	Input hysteresis				0.5		V
	Input resistance	$T_A = 25^{\circ}C$		3	5	7	kΩ

(1) Typical values are at V_{CC} = V_L = 3.3 V, T_A = 25°C

Switching Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 \text{ V}$ to 5.5 V, C1–C4 = 0.1 µF (tested at 3.3 V ± 10%), C1 = 0.047 µF, C2–C4 = 0.33 µF (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

PARAMETER		TEST CONDITIONS		UNIT
t _{PHL}	Receiver propagation dolog	People or input to receiver output $C = 150 \text{ pc}$	0.15	
t _{PLH}	Receiver propagation delay	Receiver input to receiver output, $C_L = 150 \text{ pF}$		μs
t _{PHL} – t _{PLH}	Receiver skew		50	ns
t _{en}	Receiver output enable time	From PWRDWN	200	ns
t _{dis}	Receiver output disable time	From PWRDWN	200	ns

(1) Typical values are at V_{CC} = V_L = 3.3 V, T_A = 25°C.

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DRIVER SECTION

Electrical Characteristics

over operating free-air temperature range, $V_{CC} = V_L = 3 V$ to 5.5 V, C1–C4 = 0.1 µF (tested at 3.3 V ± 10%), C1 = 0.047 µF, C2–C4 = 0.33 µF (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	Output voltage swing	All driver outputs loaded with 3 k Ω to ground	±5	±5.4		V
r _O	Output resistance	$V_{CC} = V + = V - = 0$, Driver output = ±2 V	300	10M		Ω
I _{OS}	Output short-circuit current	$V_{T_OUT} = 0$			±60	mA
I _{OZ}	Output leakage current	$V_{T_OUT} = \pm 12$ V, Driver disabled, $V_{CC} = 0$ or 3 V to 5.5 V			±25	μA
	Driver input hysteresis				0.5	V
	Input leakage current	DIN, PWRDWN		±0.01	±1	μA

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}$, $T_A = 25^{\circ}C$

Timing Requirements

over operating free-air temperature range, $V_{CC} = V_L = 3 V$ to 5.5 V, C1–C4 = 0.1 µF (tested at 3.3 V ± 10%), C1 = 0.047 µF, C2–C4 = 0.33 µF (tested at 5 V ± 10%), T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

	PARAMETER			MIN	TYP ⁽¹⁾	MAX	UNIT
	Maximum data rate	$R_L = 3 k\Omega, C_L = 1000 pF, C$	$R_L = 3 \text{ k}\Omega$, $C_L = 1000 \text{ pF}$, One driver switching				kbps
	Time-to-exit powerdown	V _{T_OUT} > 3.7 V			100		μs
t _{PHL} – t _{PLH}	Driver skew ⁽²⁾				100		ns
		$V_{CC} = 3.3 V,$ $T_A = 25^{\circ}C,$	$C_{L} = 150 \text{ pF} \text{ to } 1000 \text{ pF}$	6		30	
	$R_1 = 3 k\Omega \text{ to } 7 k\Omega.$	C _L = 150 pF to 2500 pF	4		30	V/µs	

(1) Typical values are at $V_{CC} = V_L = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. (2) Driver skew is measured at the driver zero crosspoint.

ESD Protection

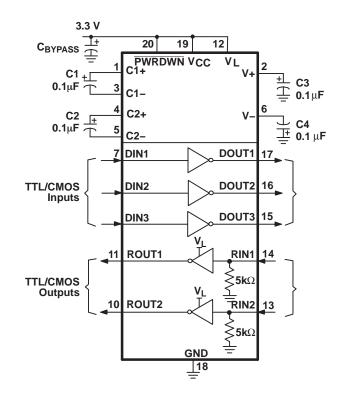
PARAMETER	TEST CONDITIONS	TYP	UNIT
RIN, DOUT	Human-Body Model	±15	
	IEC 61000-4-2 Air-Gap Discharge	±15	kV
	IEC 61000-4-2 Contact Discharge	±8	

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APPLICATION INFORMATION



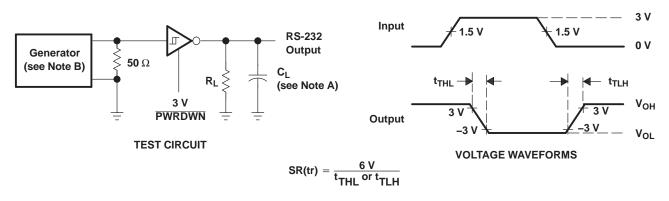
TRS3386E

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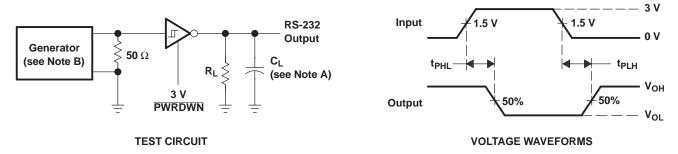
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- NOTES: A. CL includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_0 = 50 Ω , 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.

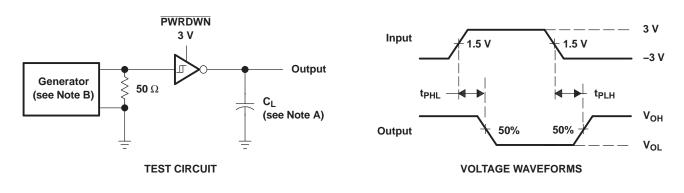




NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew



NOTES: A. C_L includes probe and jig capacitance. B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times

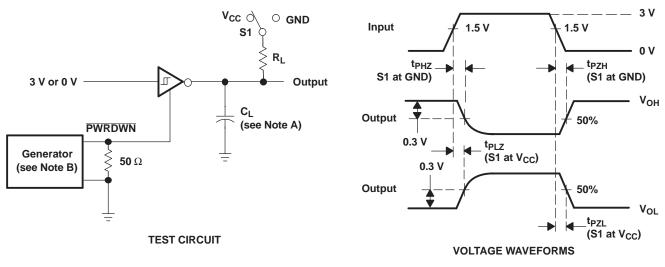
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NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 4. Receiver Enable and Disable Times

REVISION HISTORY

CI	hanges from Revision B (April 2009) to Revision C	Page
•	Changed V _L Pin for Compatibility With Mixed-Voltage Systems Down to 2.5 V (originally 1.8 V) on the Logic Side	1
•	Changed V _L Supply MIN value from 1.65 V to 2.25 V.	4
•	Deleted V _L = 1.65V parameter from Input logic threshold low.	4
•	Deleted V _L = 1.95V parameter from Input logic threshold high.	4



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24-Sep-2015

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TRS3386ECDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS3386EC	Samples
TRS3386ECDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS3386EC	Samples
TRS3386ECPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC	Samples
TRS3386ECPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC	Samples
TRS3386ECPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RV86EC	Samples
TRS3386EIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS3386EI	Samples
TRS3386EIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV86EI	Samples
TRS3386EIPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV86EI	Samples
TRS3386EIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV86EI	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



24-Sep-2015

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS3386ECDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
TRS3386ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TRS3386EIDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
TRS3386EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS3386ECDWR	SOIC	DW	20	2000	367.0	367.0	45.0
TRS3386ECPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
TRS3386EIDWR	SOIC	DW	20	2000	367.0	367.0	45.0
TRS3386EIPWR	TSSOP	PW	20	2000	367.0	367.0	38.0

DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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